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Please amend the claims as follows:

34. (Amended) The pre-formed solder mask of claim 33, wherein said <u>at least one open</u> aperture is configured to be positioned over and to expose a non-peripheral region of said contact pad.

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37. (Amended) The pre-formed solder mask of claim 33, wherein said solder mask material shrinks or degrades upon exposure to at least one of radiation, a plasma, [or] and a shrinking agent.

Please add the following new claims:

-- 41. The pre-formed solder mask of claim 33, wherein said layer is configured to be adhered to a substrate.

42. The pre-formed solder mask of claim 33, comprising an adhesive on a surface of said layer.

43.

A pre-formed solder mask, comprising:

a layer of non-metallic solder mask material having a substantially uniform thickness, said layer including a surface configured to be adhered to a substrate; and

at least one open aperture formed through said layer and located correspondingly to a contact pad location of a substrate upon which the pre-formed solder mask is to be disposed.

- 44. The pre-formed solder mask of claim 43, wherein said at least one open aperture is configured to be positioned over and to expose a non-peripheral region of said contact pad.
- 45. The pre-formed solder mask of claim 43, wherein said substantially uniform thickness of said layer substantially corresponds to a desired height of a conductive structure to be formed on said contact pad.

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- 46. The pre-formed solder mask of claim 43, wherein said solder mask material comprises a polymer.
- 47. The pre-formed solder mask of claim 43, wherein said solder mask material shrinks or degrades upon exposure to radiation, a plasma, or a shrinking agent.
- 48. The pre-formed solder mask of claim 43, wherein said surface of said layer includes an adhesive material.

>49. A semiconductor device assembly, comprising:

a substrate including at least one contact pad;

a pre-formed layer of non-metallic solder mask material disposed on said substrate, said pre-

formed layer having a substantially uniform thickness; and

at least one open aperture formed through said pre-formed layer and located correspondingly to said at least one contact pad.

- 50. The semiconductor device assembly of claim 49, further comprising a conductive structure substantially filling said at least one open aperture and in communication with said at least one contact.
- 51. The semiconductor device assembly of claim 50, wherein said conductive structure protrudes beyond an exposed surface of said pre-formed layer.
- 52. The semiconductor device assembly of claim 49, wherein said at least one open aperture is positioned over and exposes a non-peripheral region of said at least one contact pad.
- 53. The semiconductor device assembly of claim 49, wherein said substantially uniform thickness of said pre-formed layer is substantially equal to a height of said conductive structure.

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54. The semiconductor device assembly of claim 49, wherein said solder mask material comprises a polymer.

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55. The semiconductor device assembly of claim 49, wherein said solder mask material shrinks or degrades upon exposure to at least one of radiation, a plasma, and a shrinking agent.

56. The semiconductor device assembly of claim 49, wherein said surface of said preformed layer includes an adhesive material.--

An early Office Action on the merits is respectfully solicited.

Respectfully submitted,

Brick G. Power

Registration No. 38,581

Attorney for Applicants

TRASK BRITT

P. O. Box 2550

Salt Lake City, Utah 84110-2550

Telephone: (801) 532-1922

BGP/ps:dip

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